

μClamp0571P-μClamp3671P

High-Power μClamp®
1-Line Surge Protection

PROTECTION PRODUCTS

Description

μClamp® TVS diodes are designed to protect sensitive electronics from damage or latch-up due to EOS, lightning, CDE, and ESD. They feature large cross-sectional area junctions for conducting high transient currents. These devices offer desirable characteristics for board level protection including fast response time, low operating and clamping voltage, and no device degradation.

The μ Clamp®xx71P is in a DFN 1.6 x 1.0 x 0.50mm-2 Lead package, the leads are finished with lead-free NiPdAu. They may be used to protect 5V, 8V, 10V, 12V, 15V, 18V, 22V, 26V, and 36V systems. They feature high surge current capability and low clamping voltage making them ideal for use in harsh transient environments. They are qualified to AEC-Q100 (Grade 1) for automotive applications.

Features

- Transient protection for high-speed data lines to
- IEC 61000-4-2 (ESD) 30kV (air), 30kV (contact)
- IEC 61000-4-4 (EFT) 40A (5/50ns)
- IEC 61000-4-5 (Lightning) 20 80A (8/20μs)
- Protects one data or power line
- Qualified to AEC-Q100, Grade 1
- Low leakage current
- High peak pulse current capability
- Operating voltage options: 5V, 8V, 10V, 12V, 15V,
- 18V, 22V, 26V, 36V
- Solid-state silicon-avalanche technology

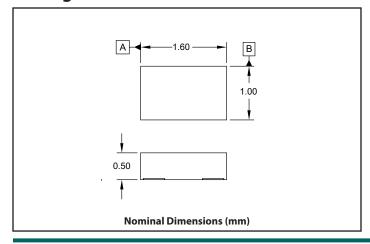
Mechanical Characteristics

- Package: DFN 1.6 x 1.0 x 0.50mm-2 Lead
- Pb-Free, Halogen Free, RoHS/WEEE Compliant
- Lead Finish: NiPdAu
- Marking: Marking code
- Packaging: Tape and Reel

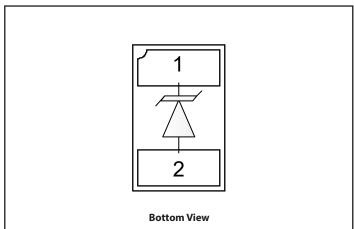
Applications

- Cellular Handsets & Accessories
- USB Voltage Bus
- Battery Protection
- Digital Lines
- Proximity Sensors
- Automotive applications

Package Dimension



Schematic & Pin Configuration



Absolute Maximum Rating

Rating	Symbol	Value	Units
Peak Pulse Power (tp = $8/20\mu s$)	P _{PK}	1200-1500	W
ESD per IEC 61000-4-2 (Air) ¹ ESD per IEC 61000-4-2 (Contact) ¹	V _{ESD}	±30 ±30	kV
Operating Temperature	T _{OP}	-40 to +125	оС
Storage Temperature	T _{STG}	-55 to +150	оС

Electrical Characteristics (T=25°C unless otherwise specified)

μClamp0571P								
Parameter	Symbol	Conditions		Min.	Тур.	Max.	Units	
Reverse Stand-Off Voltage	V _{RWM}	Pin 1 to 2				5	V	
Reverse Breakdown Voltage	V _{BR}	I _{BR} = 1mA, Pin 1 to 2		6	7	9	V	
Reverse Leakage Current	I _R	$V_{RWM} = 5V$	T = 25°C		<10	100	nA	
Peak Pulse Current	 pp	tp = 8/20μs, Pin 1 to 2				80	А	
ci v i	.,	$tp = 8/20\mu s$ $I_{pp} = 40A$ $I_{pp} = 80A$				10	.,	
Clamping Voltage	V _c					15	V	
Dynamic Resistance ^{2,3}	R _{DYN}	tp = 0.2/100ns			0.05		Ω	
Junction Capacitance	C _J	$V_R = 0V, f = 1MHz$				675	pF	

μClamp0871P								
Parameter	Symbol	Conditions		Min.	Тур.	Max.	Units	
Reverse Stand-Off Voltage	V _{RWM}	Pin 1 to 2				8	V	
Reverse Breakdown Voltage	V _{BR}	I _{BR} = 1mA, Pin 1 to 2		9.5	11	13	V	
Reverse Leakage Current	I _R	$V_{RWM} = 8V$	T = 25°C		<10	100	nA	
Peak Pulse Current	l _{pp}	tp = 8/20μs, Pin 1 to 2				65	A	
Character a Vallage		$tp = 8/20\mu s$ $I_{pp} = 10A$ $I_{pp} = 65A$				15		
Clamping Voltage	V _C					23 V		
Dynamic Resistance ^{2,3}	R _{DYN}	tp = 0.2/100ns			0.05		Ω	
Junction Capacitance	C _J	$V_R = 0V, f = 1MHz$				475	рF	

Electrical Characteristics (T=25°C unless otherwise specified)

μClamp1071P Symbol **Conditions** Min. Units **Parameter** Typ. Max. $V_{\text{RW}\underline{\text{M}}}$ ٧ Reverse Stand-Off Voltage Pin 1 to 2 10 $V_{_{BR}}$ ٧ Reverse Breakdown Voltage $I_{BR} = 1 \text{ mA}$, Pin 1 to 2 12 13.5 15.5 Reverse Leakage Current $V_{RWM} = 10V, Pin 1 to 2$ I_R $T = 25^{\circ}C$ <10 100 nΑ l_{pp} Peak Pulse Current $tp = 8/20\mu s$, Pin 1 to 2 60 Α $I_{pp} = 10A$ 17 V_{c} Clamping Voltage ٧ $tp = 8/20 \mu s$ $I_{pp} = 60A$ 25 Dynamic Resistance^{2,3} $R_{\scriptscriptstyle DYN}$ tp = 0.2/100ns0.05 Ω C_{J} **Junction Capacitance** $V_{R} = 0V, f = 1MHz$ 350 рF

μClamp1271P								
Parameter	Symbol	Conditions		Min.	Тур.	Max.	Units	
Reverse Stand-Off Voltage	V _{RWM}	Pin 1 to 2				12	V	
Reverse Breakdown Voltage	V _{BR}	I _{BR} = 1mA, Pin 1 to 2		14	16	19	V	
Reverse Leakage Current	I _R	V _{RWM} = 12V, Pin 1 to 2	T = 25°C		<10	100	nA	
Peak Pulse Current	l _{pp}	tp = 8/20μs , Pin 1 to 2				45	Α	
Clause in a Valta and		10/20	$I_{pp} = 10A$			22		
Clamping Voltage	V _C	$tp = 8/20\mu s$ $I_{pp} = 45A$				30	V	
Dynamic Resistance ^{2,3}	R _{DYN}	tp = 0.2/100ns			0.05		Ω	
Junction Capacitance	C _J	$V_R = 0V, f = 1MHz$				275	pF	

μClamp1571P								
Parameter	Symbol	Conditions		Min.	Тур.	Max.	Units	
Reverse Stand-Off Voltage	V _{RWM}	Pin 1 to 2				15	V	
Reverse Breakdown Voltage	V _{BR}	I _{BR} = 1mA, Pin 1 to 2		17.5	20	23	V	
Reverse Leakage Current	I _R	V _{RWM} = 15V, Pin 1 to 2	T = 25°C		<10	100	nA	
Peak Pulse Current	l _{pp}	tp = 8/20μs , Pin 1 to 2				40	А	
Clause in a Valta as	V	$tp = 8/20 \mu s$ $I_{pp} = 10 A$ $I_{pp} = 40 A$				25	V	
Clamping Voltage	V _C					40	V	
Dynamic Resistance ^{2,3}	R _{DYN}	tp = 0.2/100ns			0.05		Ω	
Junction Capacitance	C _J	$V_R = 0V, f = 1MHz$				220	pF	

μClamp1871P								
Parameter	Symbol	Conditions		Min.	Тур.	Max.	Units	
Reverse Stand-Off Voltage	V _{RWM}	Pin 1 to 2				18	V	
Reverse Breakdown Voltage	V _{BR}	I _{BR} = 1mA, Pin 1 to 2		20	22	25	V	
Reverse Leakage Current	I _R	$V_{RWM} = 18V, Pin1 \text{ to } 2$ $T = 25^{\circ}C$			<10	100	nA	
Peak Pulse Current	I _{pp}	tp = 8/20μs , Pin 1 to 2	tp = 8/20μs , Pin 1 to 2			35	Α	
Clause in a Valta and		$tp = 8/20 \mu s$ $I_{pp} = 10 A$ $I_{pp} = 35 A$				28		
Clamping Voltage	V _C					45	V	
Dynamic Resistance ^{2,3}	R _{DYN}	tp = 0.2/100ns			0.10		Ω	
Junction Capacitance	C _J	$V_R = 0V, f = 1MHz$				225	pF	

μClamp2271P								
Parameter	Symbol	Conditions		Min.	Тур.	Max.	Units	
Reverse Stand-Off Voltage	V _{RWM}	Pin 1 to 2				22	V	
Reverse Breakdown Voltage	V _{BR}	I _{BR} = 1mA, Pin 1 to 2		25.5	29	33.5	V	
Reverse Leakage Current	I _R	$V_{RWM} = 22V$, Pin 1 to 2 $T = 25^{\circ}C$			<10	100	nA	
Peak Pulse Current	l _{pp}	tp = 8/20μs , Pin 1 to 2				25	Α	
Clamping Voltage	V	tn = 9/20us Din 1 to 2	I _{PP} = 10A			40	V	
Clamping Voltage	V _C	tp = 8/20µs, Pin 1 to 2 $I_{pp} = 25A$				55	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	
Dynamic Resistance ^{2,3}	R _{DYN}	tp = 0.2/100ns			0.10		Ω	
Junction Capacitance	C _J	$V_R = 0V, f = 1MHz$				165	рF	

μClamp2671P								
Parameter	Symbol	Conditions		Min.	Тур.	Max.	Units	
Reverse Stand-Off Voltage	V _{RWM}	Pin 1 to 2				26	V	
Reverse Breakdown Voltage	V _{BR}	I _{BR} = 1mA, Pin 1 to 2		29	32	35	V	
Reverse Leakage Current	I _R	$V_{RWM} = 5V$	T = 25°C		<10	100	nA	
Peak Pulse Current	I _{pp}	tp = 8/20μs , Pin 1	to 2			23	Α	
Clausein a Valta aa	V	$tp = 8/20 \mu s$ $I_{pp} = 10 A$ $I_{pp} = 23 A$				50	.,	
Clamping Voltage	V _C					65	V	
Dynamic Resistance ^{2,3}	R _{DYN}	tp = 0.2/100ns			0.15		Ω	
Junction Capacitance	C _J	$V_R = 0V, f = 1MHz$				155	pF	

μClamp3671P **Symbol Conditions Units Parameter** Min. Typ. Max. Reverse Stand-Off Voltage $\boldsymbol{V}_{\text{RWM}}$ Pin 1 to 2 ٧ 36 $\boldsymbol{V}_{_{BR}}$ ٧ Reverse Breakdown Voltage $I_{BR} = 1 \text{ mA}$, Pin 1 to 2 37 44 Reverse Leakage Current I_R $V_{RWM} = 36V$ $T = 25^{\circ}C$ <10 100 nΑ Peak Pulse Current l_{pp} $tp = 8/20 \mu s$, Pin 1 to 2 Α 18 $I_{pp} = 2A$ 48 Clamping Voltage V_{c} ٧ $tp = 8/20 \mu s$ $I_{pp} = 18A$ 80 tp = 0.2/100nsDynamic Resistance^{2,3} 0.29 $\boldsymbol{R}_{\text{DYN}}$ Ω **Junction Capacitance** C, $V_D = 0V, f = 1MHz$ 150 рF

Notes:

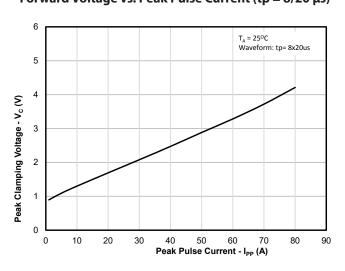
- 1) ESD gun return path connected to ESD ground plane.
- 2) Transmission Line Pulse Test (TLP) Settings: tp = 100ns, tr = 0.2ns, I_{TLP} and V_{TLP} averaging window: t1 = 70ns to t2 = 90ns.
- 3) Dynamic resistance calculated from $I_{TLP} = 4A$ to $I_{TLP} = 16A$

Typical Characteristics

Non-Repetitive Peak Pulse Power vs. Pulse Time

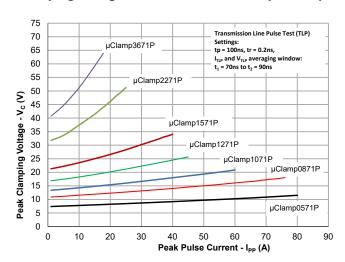
100 T_A = 25°C (Ny) a 10 1500W @ 20µS 1350W @ 20µS 100 Pulse Duration - tp (µs)

Forward Voltage vs. Peak Pulse Current (tp = 8/20 μs)

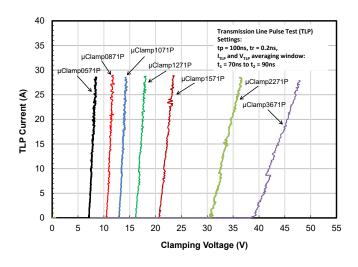


ESD Clamping - μClamp0571P (+8kV Contact per IEC 61000-4-2) 35 30 25 Clamping Voltage - V_c (V) 20 15 10 5 Measured with 50 Ohm scope input impedance, 2GHz bandwidth. Corrected 0 for 50 Ohm, 20dB attenuator. ESD gun return path connected to ESD ground plane -5 0 10 20 30 40 50 60 70 80 Time (ns)

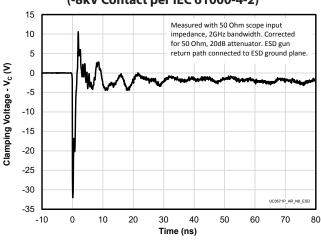
Clamping Voltage vs. Peak Pulse Current (tp = 8/20 µs)



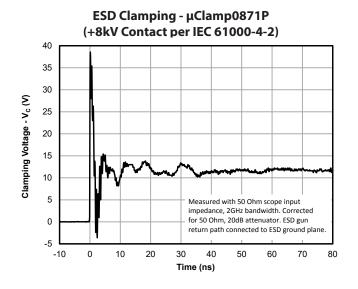
TLP Characteristic

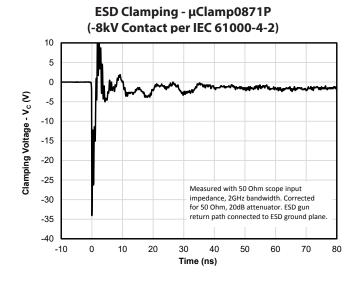


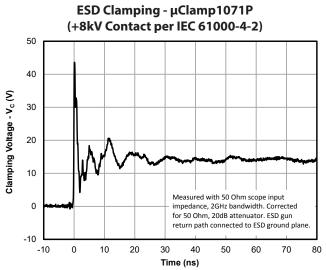
ESD Clamping - μClamp0571P (-8kV Contact per IEC 61000-4-2)

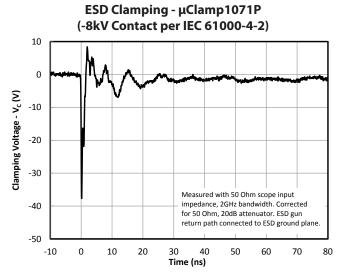


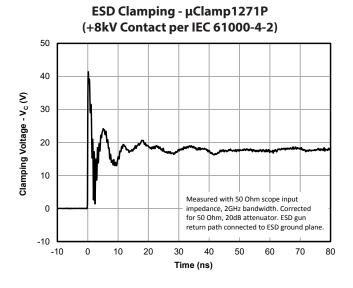
Typical Characteristics (Continued)

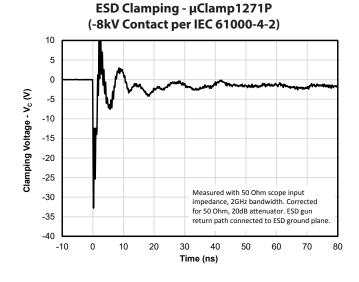




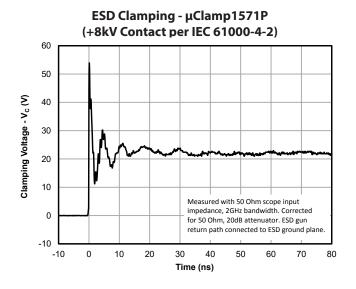


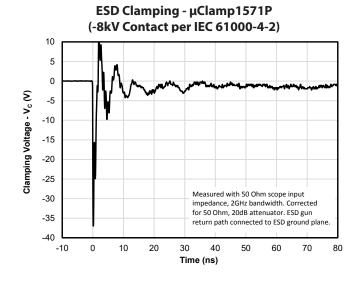


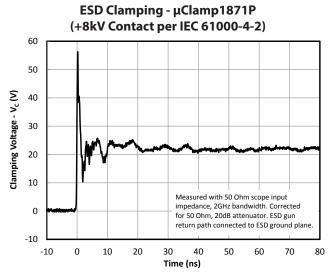


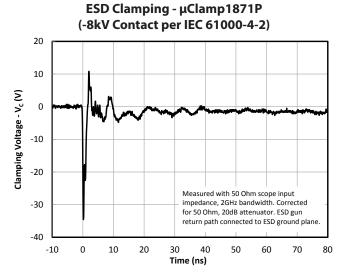


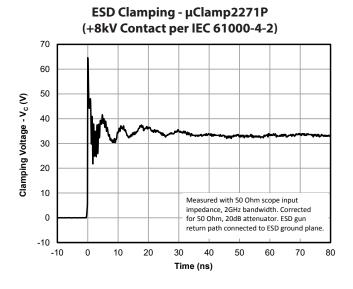
Typical Characteristics (Continued)

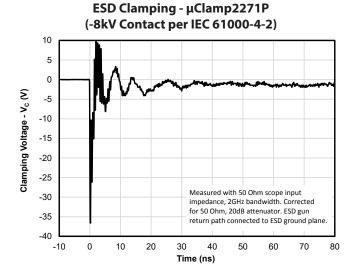




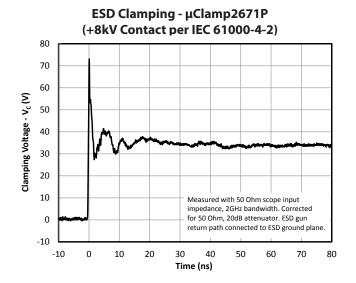


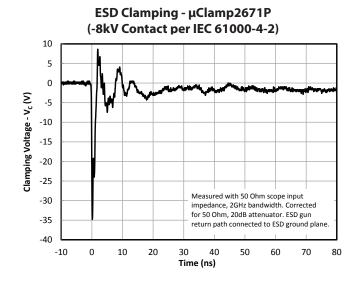


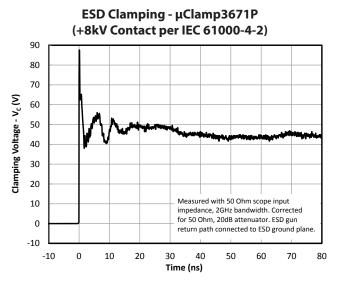


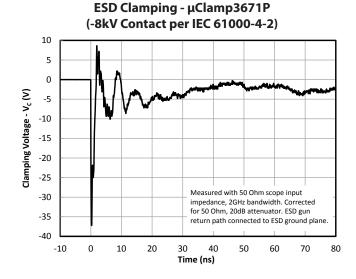


Typical Characteristics (Continued)







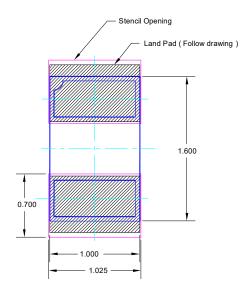


Application Information

Assembly Guidelines

The table below provides Semtech's recommended assembly guidelines for mounting this device. The figure at the right details Semtech's recommended aperture based on the below recommendations. Note that these are only recommendations and should serve only as a starting point for design since there are many factors that affect the assembly process. The exact manufacturing parameters will require some experimentation to get the desired solder application.

Assembly Parameter	Recommendation
Solder Stencil Design	Laser cut, Electro-polished
Aperture shape	Rectangular with rounded corners
Solder Stencil Thickness	0.125 mm (0.005")
Solder Paste Type	Type 3 size sphere or smaller
Solder Reflow Profile	per JEDEC J-STD-020
PCB Solder Pad Design	Non-Solder mask defined
PCB Pad Finish	OSP OR NiAu

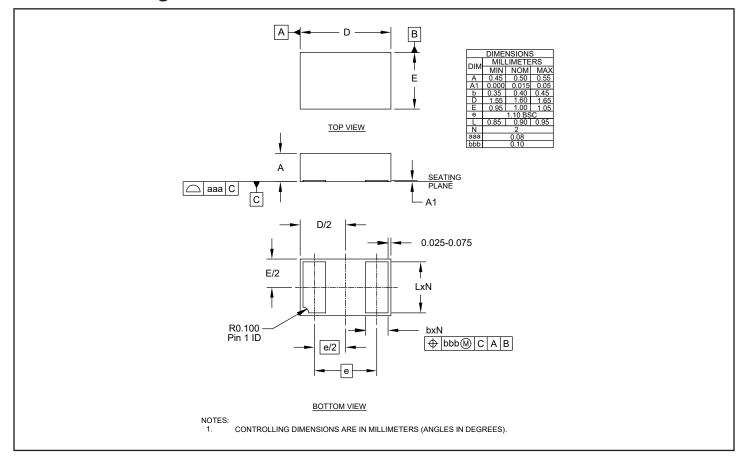


All Dimensions are in mm.

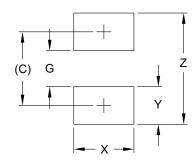
Land Pad. Stencil opening Component

Recommended Mounting Pattern

Outline Drawing - DFN 1.6 x 1.0 x 0.50-2 Lead



Land Pattern - DFN 1.6 x 1.0 x 0.50-2 Lead



DIMENSIONS						
DIM MILLIMETERS						
C	(1.225)					
G	0.60					
Χ	1.00					
Y	0.625					
Z	1.85					

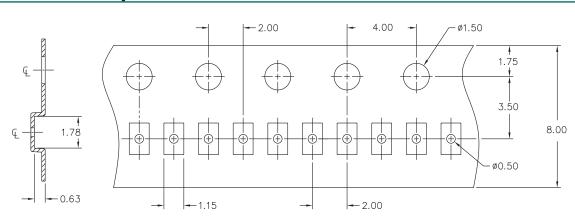
NOTES:

- 1. CONTROLLING DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREES).
- 2. THIS LAND PATTERN IS FOR REFERENCE PURPOSES ONLY.
 CONSULT YOUR MANUFACTURING GROUP TO ENSURE YOUR
 COMPANY'S MANUFACTURING GUIDELINES ARE MET.

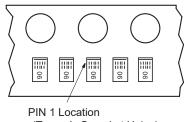
Marking Code



Tape and Reel Specification



Note: All dimension are nominal dimensions in mm



(Towards Sprocket Holes)

Ordering Information

Part Number	Marking Code	Working Voltage	Qty per Reel
μClamp0571P.TNT	06	5V	10,000
μClamp0871P.TNT	11	8V	10,000
μClamp1071P.TNT	12	10V	10,000
μClamp1271P.TNT	16	12V	10,000
μClamp1571P.TNT	18	15V	10,000
μClamp1871P.TNT	24	18V	10,000
μClamp2271P.TNT	26	22V	10,000
μClamp2671P.TNT	30	26V	10,000
μClamp3671P.TNT	37	36V	10,000



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